

BA157 - BA159

FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 400 - 1000V CURRENT: 1.0 A

Features

Diffused Junction

Low Forward Voltage Drop

High Current Capability

High Reliability

High Surge Current Capability

Mechanical Data

Case: D O - 4 1 Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

Polarity: Cathode Band

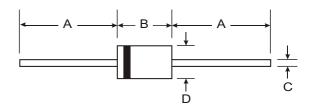
Weight: 0.34 grams (approx.)

Mounting Position: Any

Marking: Type Number







DO-41					
Dim	Min	Max			
Α	25.40	_			
В	4.06	5.21			
С	0.71	0.864			
D	2.00	2.72			
All Dimensions in mm					

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

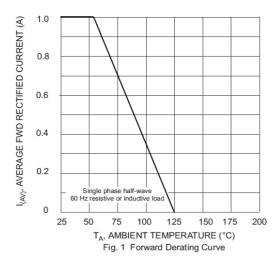
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

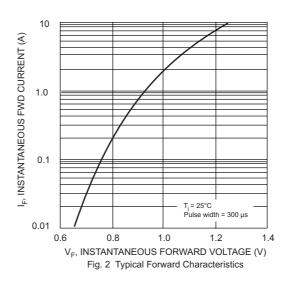
Characteristic	Symbol	BA157	BA158	BA159	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	400	600	1000	V
RMS Reverse Voltage	VR(RMS)	280	420	700	V
Average Rectified Output Current (Note 1) @T _A = 55°C	lo		1.0		А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM		30		А
Forward Voltage $@I_F = 1.0A$	VFM	1.2			V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	 RM	5.0 100			μΑ
Reverse Recovery Time (Note 2)	trr	150	250	500	nS
Typical Junction Capacitance (Note 3)	Cj		15		pF
Operating Temperature Range	Tj	-65 to +125		°C	
Storage Temperature Range	Тѕтс	-65 to +150		°C	

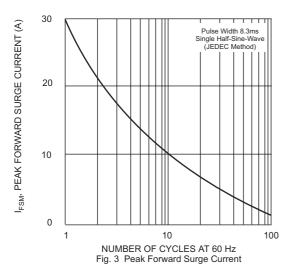
Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

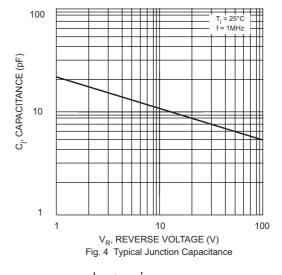
- 2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

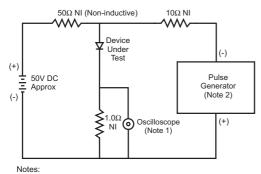


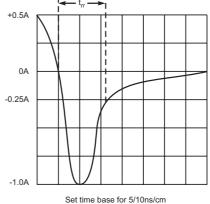












1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF. 2. Rise Time = 10ns max. Input Impedance = 50Ω .

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit